NSN 5961-00-809-1880

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-809-1880 **Inclosure Material:** Metal **Overall Length:** 0.687 inches **Overall Diameter:** 0.281 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud Features Provided: Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 1.60 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug **Specification Data:** 80131-release2114 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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